NSN 5961-01-332-8094

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-332-8094 **Inclosure Material:** Ceramic and metal **Overall Length:** Between 0.515 inches and 0.565 inches **Overall Diameter:** Between 1.600 inches and 1.656 inches **Mounting Method:** Compression **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 repetitive peak reverse voltage and 200.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 500.00 amperes forward current, total rms horsepower metric and 310.00 amperes drain current universal **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 case and 2 insulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: